Infineon Technologies - CY8C3865AXA-018 Datasheet

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	8051
Core Size	8-Bit
Speed	67MHz
Connectivity	EBI/EMI, I²C, LINbus, SPI, UART/USART
Peripherals	CapSense, DMA, LCD, POR, PWM, WDT
Number of I/O	62
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	1K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 16x20b; D/A 4x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c3865axa-018

It also contains a separate, very low-power internal low-speed oscillator (ILO) for the sleep and watchdog timers. A 32.768-kHz external watch crystal is also supported for use in real-time clock (RTC) applications. The clocks, together with programmable clock dividers, provide the flexibility to integrate most timing requirements.

The CY8C38 family supports a wide supply operating range from 1.71 V to 5.5 V. This allows operation from regulated supplies such as 1.8 V ± 5%, 2.5 V ±10%, 3.3 V ± 10%, or 5.0 V ± 10%, or directly from a wide range of battery types.

PSoC supports a wide range of low-power modes. These include a 200-nA hibernate mode with RAM retention and a 1-µA sleep mode with RTC. In the second mode, the optional 32.768-kHz watch crystal runs continuously and maintains an accurate RTC.

Power to all major functional blocks, including the programmable digital and analog peripherals, can be controlled independently by firmware. This allows low-power background processing when some peripherals are not in use. This, in turn, provides a total device current of only 1.2 mA when the CPU is running at 6 MHz, or 0.8 mA running at 3 MHz.

The details of the PSoC power modes are covered in the "Power System" section on page 29 of this data sheet.

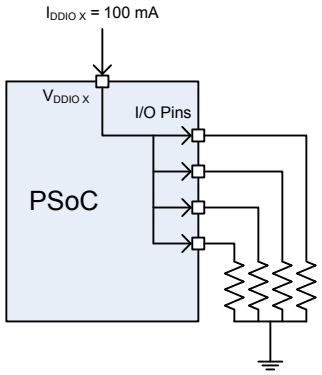
PSoC uses JTAG (4-wire) or SWD (2-wire) interfaces for programming, debug, and test. The 1-wire SWV may also be used for 'printf' style debugging. By combining SWD and SWV, you can implement a full debugging interface with just three pins. Using these standard interfaces you can debug or program the PSoC with a variety of hardware solutions from Cypress or third party vendors. PSoC supports on-chip break points and 4-KB instruction and data race memory for debug. Details of the programming, test, and debugging interfaces are discussed in the "Programming, Debug Interfaces, Resources" section on page 60 of this data sheet.

2. Pinouts

Each VDDIO pin powers a specific set of I/O pins. (The USBIOs are powered from VDDD.) Using the VDDIO pins, a single PSoC can support multiple voltage levels, reducing the need for off-chip level shifters. The black lines drawn on the pinout diagrams in Figure 2-3 through Figure 2-4 show the pins that are powered by each VDDIO.

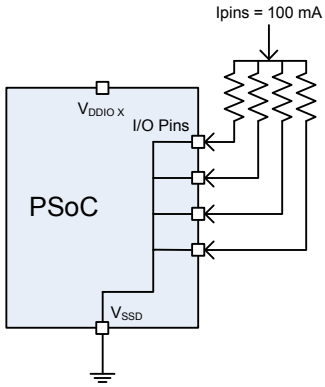
Each VDDIO may source up to 100 mA [8] total to its associated I/O pins, as shown in Figure 2-1.

Figure 2-1. VDDIO Current Limit



Conversely, for the 100-pin and 68-pin devices, the set of I/O pins associated with any VDDIO may sink up to 100 mA [8] total, as shown in Figure 2-2.

Figure 2-2. I/O Pins Current Limit



For the 48-pin devices, the set of I/O pins associated with VDDIO0 plus VDDIO2 may sink up to 100 mA [8] total. The set of I/O pins associated with VDDIO1 plus VDDIO3 may sink up to a total of 100 mA.

Note
8. The 100 mA source/ sink current per Vddio is valid only for temperature range of –40 °C to +85 °C. For extended temperature range of –40 °C to +125 °C, the maximum source or sink current per Vddio is 40 mA.

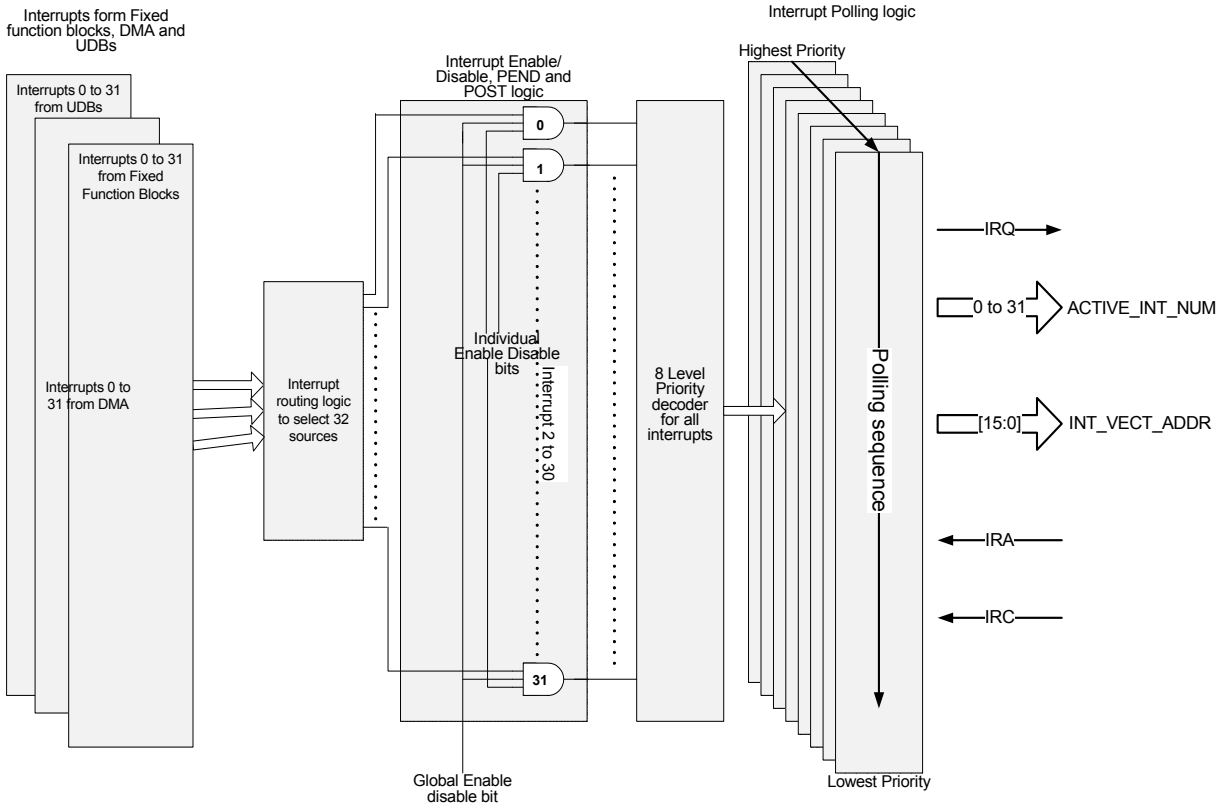
Table 4-3. Data Transfer Instructions

Mnemonic	Description	Bytes	Cycles
MOV A,Rn	Move register to accumulator	1	1
MOV A,Direct	Move direct byte to accumulator	2	2
MOV A,@Ri	Move indirect RAM to accumulator	1	2
MOV A,#data	Move immediate data to accumulator	2	2
MOV Rn,A	Move accumulator to register	1	1
MOV Rn,Direct	Move direct byte to register	2	3
MOV Rn, #data	Move immediate data to register	2	2
MOV Direct, A	Move accumulator to direct byte	2	2
MOV Direct, Rn	Move register to direct byte	2	2
MOV Direct, Direct	Move direct byte to direct byte	3	3
MOV Direct, @Ri	Move indirect RAM to direct byte	2	3
MOV Direct, #data	Move immediate data to direct byte	3	3
MOV @Ri, A	Move accumulator to indirect RAM	1	2
MOV @Ri, Direct	Move direct byte to indirect RAM	2	3
MOV @Ri, #data	Move immediate data to indirect RAM	2	2
MOV DPTR, #data16	Load data pointer with 16 bit constant	3	3
MOVC A, @A+DPTR	Move code byte relative to DPTR to accumulator	1	5
MOVC A, @A + PC	Move code byte relative to PC to accumulator	1	4
MOVX A,@Ri	Move external RAM (8-bit) to accumulator	1	4
MOVX A, @DPTR	Move external RAM (16-bit) to accumulator	1	3
MOVX @Ri, A	Move accumulator to external RAM (8-bit)	1	5
MOVX @DPTR, A	Move accumulator to external RAM (16-bit)	1	4
PUSH Direct	Push direct byte onto stack	2	3
POP Direct	Pop direct byte from stack	2	2
XCH A, Rn	Exchange register with accumulator	1	2
XCH A, Direct	Exchange direct byte with accumulator	2	3
XCH A, @Ri	Exchange indirect RAM with accumulator	1	3
XCHD A, @Ri	Exchange low order indirect digit RAM with accumulator	1	3

Table 4-4. Boolean Instructions

Mnemonic	Description	Bytes	Cycles
CLR C	Clear carry	1	1
CLR bit	Clear direct bit	2	3
SETB C	Set carry	1	1
SETB bit	Set direct bit	2	3
CPL C	Complement carry	1	1
CPL bit	Complement direct bit	2	3
ANL C, bit	AND direct bit to carry	2	2

Figure 4-3. Interrupt Structure



When an interrupt is pending, the current instruction is completed and the program counter is pushed onto the stack. Code execution then jumps to the program address provided by the vector. After the ISR is completed, a RETI instruction is executed and returns execution to the instruction following the previously interrupted instruction. To do this the RETI instruction pops the program counter from the stack.

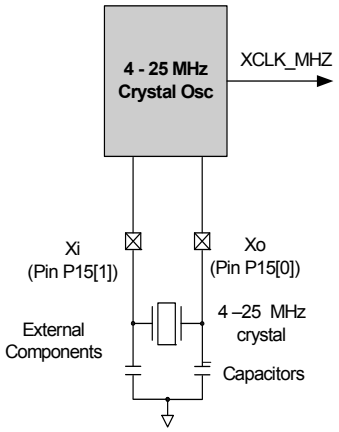
If the same priority level is assigned to two or more interrupts, the interrupt with the lower vector number is executed first. Each interrupt vector may choose from three interrupt sources: Fixed Function, DMA, and UDB. The fixed function interrupts are direct connections to the most common interrupt sources and provide the lowest resource cost connection. The DMA interrupt sources provide direct connections to the two DMA interrupt sources provided per DMA channel. The third interrupt source for vectors is from the UDB digital routing array. This allows any digital signal available to the UDB array to be used as an interrupt source. Fixed function interrupts and all interrupt sources may be routed to any interrupt vector using the UDB interrupt source connections.

6.1.2 External Oscillators

6.1.2.1 MHz External Crystal Oscillator

The MHzECO provides high frequency, high precision clocking using an external crystal (see Figure 6-2). It supports a wide variety of crystal types, in the range of 4 to 25 MHz. When used in conjunction with the PLL, it can generate other clocks up to the device's maximum frequency (see PLL). The GPIO pins connecting to the external crystal and capacitors are fixed. MHzECO accuracy depends on the crystal chosen.

Figure 6-2. MHzECO Block Diagram

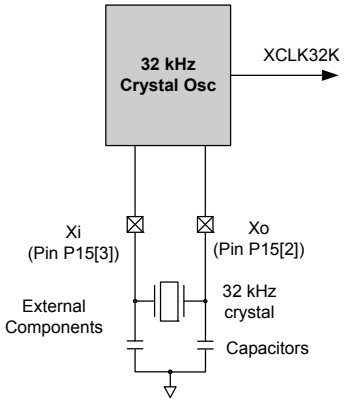


6.1.2.2 32.768-kHz ECO

The 32.768-kHz external crystal oscillator (32kHzECO) provides precision timing with minimal power consumption using an external 32.768-kHz watch crystal (see Figure 6-3). The 32kHzECO also connects directly to the sleep timer and provides the source for the RTC. The RTC uses a 1-second interrupt to implement the RTC functionality in firmware.

The oscillator works in two distinct power modes. This allows users to trade off power consumption with noise immunity from neighboring circuits. The GPIO pins connected to the external crystal and capacitors are fixed.

Figure 6-3. 32kHzECO Block Diagram



It is recommended that the external 32.768-kHz watch crystal have a load capacitance (CL) of 6 pF or 12.5 pF. Check the crystal manufacturer's datasheet. The two external capacitors, CL1 and CL2, are typically of the same value, and their total capacitance, CL1CL2 / (CL1 + CL2), including pin and trace capacitance, should equal the crystal CL value. For more information, refer to application note AN54439: PSoC 3 and PSoC 5 External Oscillators. See also pin capacitance specifications in the "GPIO" section on page 74.

6.1.2.3 Digital System Interconnect

The DSI provides routing for clocks taken from external clock oscillators connected to I/O. The oscillators can also be generated within the device in the digital system and UDBs.

While the primary DSI clock input provides access to all clocking resources, up to eight other DSI clocks (internally or externally generated) may be routed directly to the eight digital clock dividers. This is only possible if there are multiple precision clock sources.

6.1.3 Clock Distribution

All seven clock sources are inputs to the central clock distribution system. The distribution system is designed to create multiple high precision clocks. These clocks are customized for the design's requirements and eliminate the common problems found with limited resolution prescalers attached to peripherals. The clock distribution system generates several types of clock trees.

- The master clock is used to select and supply the fastest clock in the system for general clock requirements and clock synchronization of the PSoC device.
- Bus clock 16-bit divider uses the master clock to generate the bus clock used for data transfers. Bus clock is the source clock for the CPU clock divider.
- Eight fully programmable 16-bit clock dividers generate digital system clocks for general use in the digital system, as configured by the design's requirements. Digital system clocks can generate custom clocks derived from any of the seven clock sources for any purpose. Examples include baud rate generators, accurate PWM periods, and timer clocks, and many others. If more than eight digital clock dividers are required, the UDBs and fixed function timer/counter/PWMs can also generate clocks.
- Four 16-bit clock dividers generate clocks for the analog system components that require clocking, such as ADC and mixers. The analog clock dividers include skew control to ensure that critical analog events do not occur simultaneously with digital switching events. This is done to reduce analog system noise.

Each clock divider consists of an 8-input multiplexer, a 16-bit clock divider (divide by 2 and higher) that generates ~50 percent duty cycle clocks, master clock resynchronization logic, and deglitch logic. The outputs from each digital clock tree can be routed into the digital system interconnect and then brought back into the clock system as an input, allowing clock chaining of up to 32 bits.

6.1.4 USB Clock Domain

The USB clock domain is unique in that it operates largely asynchronously from the main clock network. The USB logic contains a synchronous bus interface to the chip, while running on an asynchronous clock to process USB data. The USB logic requires a 48 MHz frequency. This frequency can be generated from different sources, including DSI clock at 48 MHz or doubled value of 24 MHz from internal oscillator, DSI signal, or crystal oscillator.

6.4 I/O System and Routing

PSoC I/Os are extremely flexible. Every GPIO has analog and digital I/O capability. All I/Os have a large number of drive modes, which are set at POR. PSoC also provides up to four individual I/O voltage domains through the VDDIO pins.

There are two types of I/O pins on every device; those with USB provide a third type. Both GPIO and SIO provide similar digital functionality. The primary differences are their analog capability and drive strength. Devices that include USB also provide two USBIO pins that support specific USB functionality as well as limited GPIO capability.

All I/O pins are available for use as digital inputs and outputs for both the CPU and digital peripherals. In addition, all I/O pins can generate an interrupt. The flexible and advanced capabilities of the PSoC I/O, combined with any signal to any pin routability, greatly simplify circuit design and board layout. All GPIO pins can be used for analog input, CapSense[13], and LCD segment drive, while SIO pins are used for voltages in excess of VDDA and for programmable output voltages.

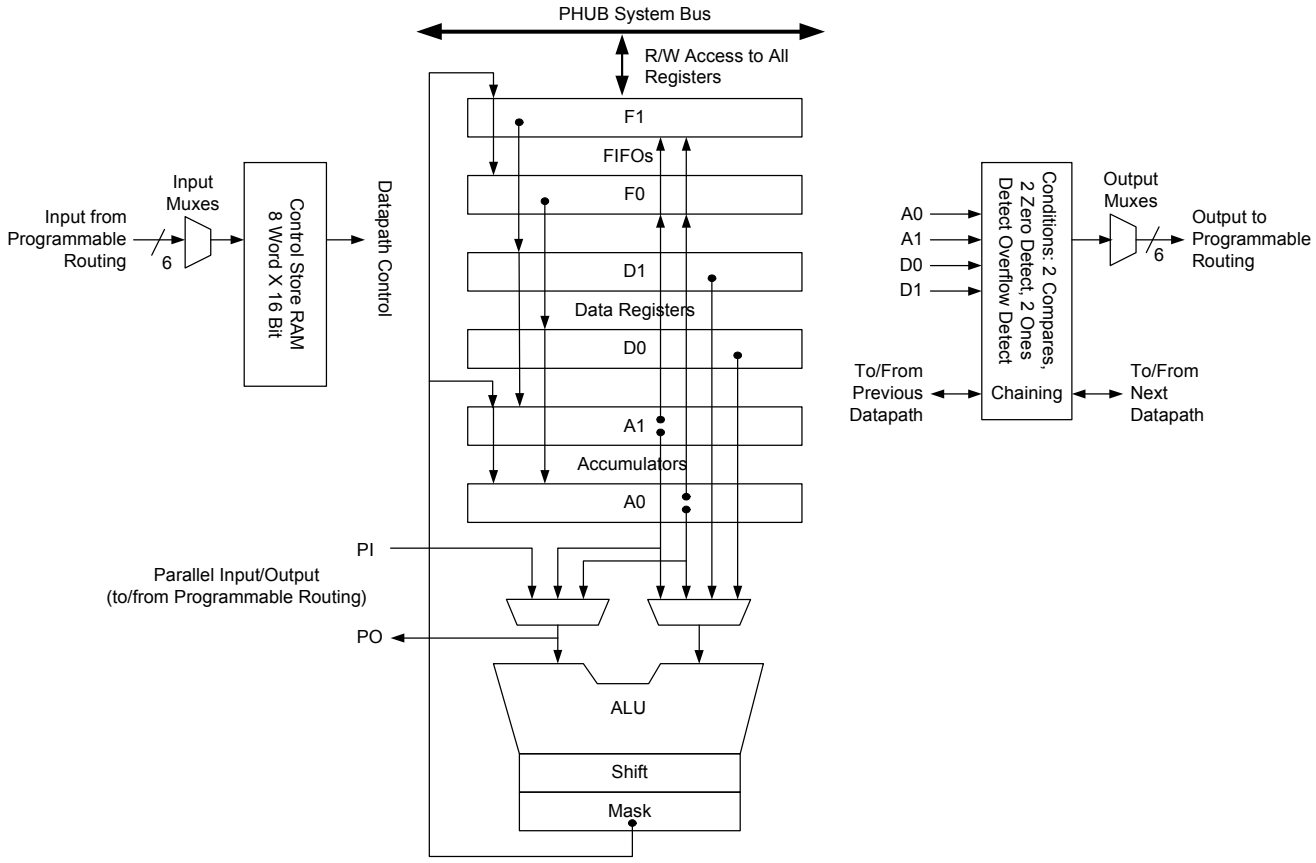
- Features supported by both GPIO and SIO:
  - User programmable port reset state
  - Separate I/O supplies and voltages for up to four groups of I/O
  - Digital peripherals use DSI to connect the pins
  - Input or output or both for CPU and DMA
  - Eight drive modes
  - Every pin can be an interrupt source configured as rising edge, falling edge or both edges. If required, level sensitive interrupts are supported through the DSI
  - Dedicated port interrupt vector for each port
  - Slew rate controlled digital output drive mode
  - Access port control and configuration registers on either port basis or pin basis
  - Separate port read (PS) and write (DR) data registers to avoid read modify write errors
  - Special functionality on a pin by pin basis
- Additional features only provided on the GPIO pins:
  - LCD segment drive on LCD equipped devices
  - CapSense[13]
  - Analog input and output capability
  - Continuous 100 µA clamp current capability
  - Standard drive strength down to 1.7 V
- Additional features only provided on SIO pins:
  - Higher drive strength than GPIO
  - Hot swap capability (5 V tolerance at any operating V_{DD})
  - Programmable and regulated high input and output drive levels down to 1.2 V
  - No analog input, CapSense, or LCD capability
  - Over voltage tolerance up to 5.5 V
  - SIO can act as a general purpose analog comparator
- USBIO features:
  - Full speed USB 2.0 compliant I/O
  - Highest drive strength for general purpose use
  - Input, output, or both for CPU and DMA
  - Input, output, or both for digital peripherals
  - Digital output (CMOS) drive mode
  - Each pin can be an interrupt source configured as rising edge, falling edge, or both edges

Note
13. GPIOs with opamp outputs are not recommended for use with CapSense.

7.2.2 Datapath Module

The datapath contains an 8-bit single cycle ALU, with associated compare and condition generation logic. This datapath block is optimized to implement embedded functions, such as timers, counters, integrators, PWMs, PRS, CRC, shifters and dead band generators and many others.

Figure 7-4. Datapath Top Level



7.2.2.1 Working Registers

The datapath contains six primary working registers, which are accessed by CPU firmware or DMA during normal operation.

Table 7-1. Working Datapath Registers

Name	Function	Description
A0 and A1	Accumulators	These are sources and sinks for the ALU and also sources for the compares.
D0 and D1	Data Registers	These are sources for the ALU and sources for the compares.
F0 and F1	FIFOs	These are the primary interface to the system bus. They can be a data source for the data registers and accumulators or they can capture data from the accumulators or ALU. Each FIFO is four bytes deep.

7.2.2.2 Dynamic Datapath Configuration RAM

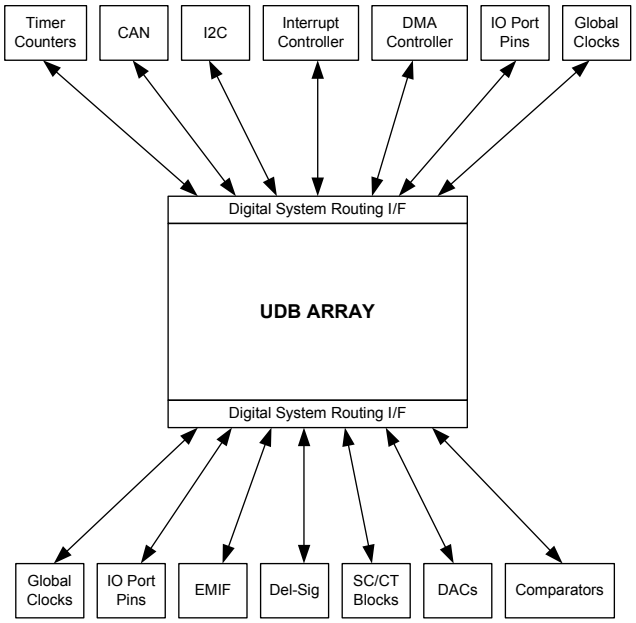
Dynamic configuration is the ability to change the datapath function and internal configuration on a cycle-by-cycle basis, under sequencer control. This is implemented using the 8-word × 16-bit configuration RAM, which stores eight unique 16-bit wide configurations. The address input to this RAM controls the sequence, and can be routed from any block connected to the UDB routing matrix, most typically PLD logic, I/O pins, or from the outputs of this or other datapath blocks.

ALU

The ALU performs eight general purpose functions. They are:

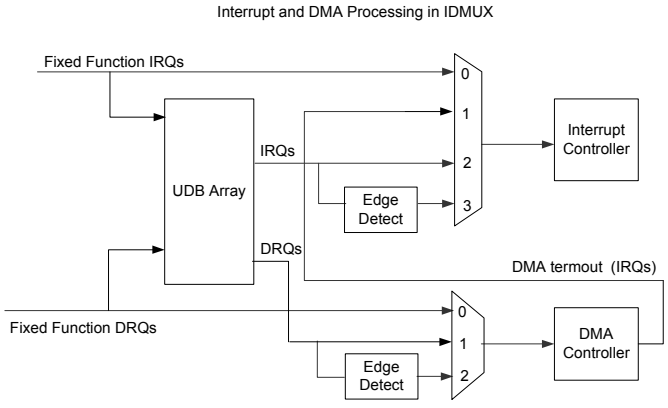
- Increment
- Decrement
- Add
- Subtract
- Logical AND
- Logical OR
- Logical XOR
- Pass, used to pass a value through the ALU to the shift register, mask, or another UDB register.

Figure 7-9. Digital System Interconnect



Interrupt and DMA routing is very flexible in the CY8C38 programmable architecture. In addition to the numerous fixed function peripherals that can generate interrupt requests, any data signal in the UDB array routing can also be used to generate a request. A single peripheral may generate multiple independent interrupt requests simplifying system and firmware design. Figure 7-10 shows the structure of the IDMUX (Interrupt/DMA Multiplexer).

Figure 7-10. Interrupt and DMA Processing in the IDMUX



7.4.1 I/O Port Routing

There are a total of 20 DSI routes to a typical 8-bit I/O port, 16 for data and four for drive strength control.

When an I/O pin is connected to the routing, there are two primary connections available, an input and an output. In conjunction with drive strength control, this can implement a bidirectional I/O pin. A data output signal has the option to be single synchronized (pipelined) and a data input signal has the option to be double synchronized. The synchronization clock is the master clock (see Figure 6-1). Normally all inputs from pins are synchronized as this is required if the CPU interacts with the signal or any signal derived from it. Asynchronous inputs have rare uses. An example of this is a feed through of combinational PLD logic from input pins to output pins.

Figure 7-11. I/O Pin Synchronization Routing

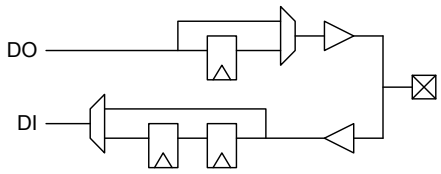
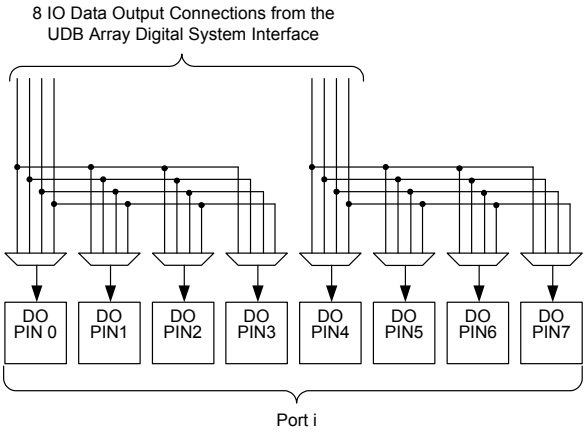
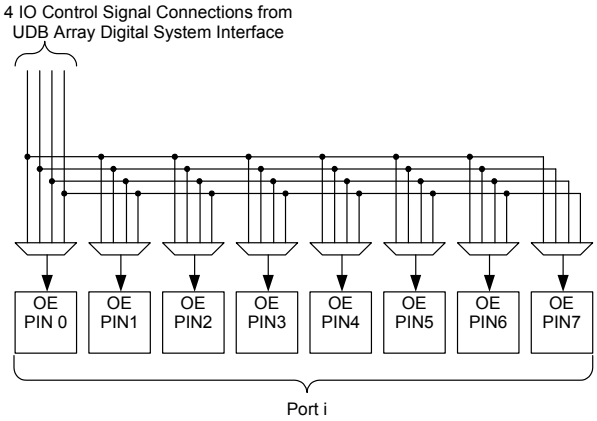


Figure 7-12. I/O Pin Output Connectivity



There are four more DSI connections to a given I/O port to implement dynamic output enable control of pins. This connectivity gives a range of options, from fully ganged 8-bits controlled by one signal, to up to four individually controlled pins. The output enable signal is useful for creating tri-state bidirectional pins and buses.

Figure 7-13. I/O Pin Output Enable Connectivity



7.9 Digital Filter Block

Some devices in the CY8C38 family of devices have a dedicated HW accelerator block used for digital filtering. The DFB has a dedicated multiplier and accumulator that calculates a 24-bit by 24-bit multiply accumulate in one bus clock cycle. This enables the mapping of a direct form FIR filter that approaches a computation rate of one FIR tap for each clock cycle. The MCU can implement any of the functions performed by this block, but at a slower rate that consumes MCU bandwidth.

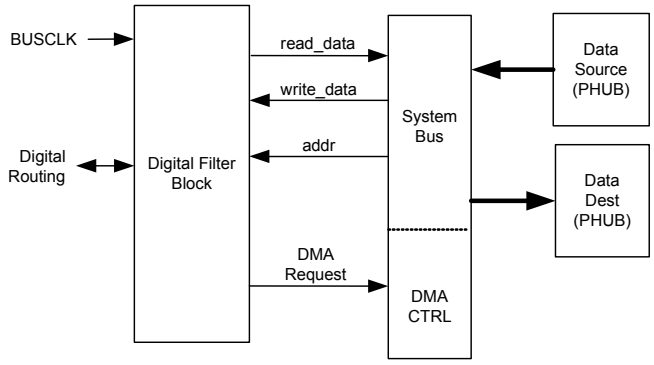
The heart of the DFB is a datapath (DP), which is the numerical calculation unit of the DFB. The DP is a 24-bit fixed-point numerical processor containing a 48-bit multiply and accumulate function (MAC), a multi-function ALU, sample and coefficient data RAMs as well as data routing, shifting, holding and rounding functions.

In the MAC, two 24-bit values can be multiplied and the result added to the 48-bit accumulator in each bus clock cycle. The MAC is the only portion of the DP that is wider than 24 bits. All results from the MAC are passed on to the ALU as 24-bit values representing the high-order 24 bits in the accumulator shifted by one (bits 46:23). The MAC assumes an implied binary point after the most significant bit.

The DP also contains an optimized ALU that supports add, subtract, comparison, threshold, absolute value, squelch, saturation, and other functions. The DP unit is controlled by seven control fields totaling 18 bits coming from the DFB Controller. For more information see the TRM.

The PSoC Creator interface provides a wizard to implement FIR and IIR digital filters with coefficients for LPF, BPF, HPF, Notch and arbitrary shape filters. 64 pairs of data and coefficients are stored. This enables a 64 tap FIR filter or up to 4 16 tap filters of either FIR or IIR formulation.

Figure 7-19. DFB Application Diagram (pwr/gnd not shown)



The typical use model is for data to be supplied to the DFB over the system bus from another on-chip system data source such as an ADC. The data typically passes through main memory or is directly transferred from another chip resource through DMA. The DFB processes this data and passes the result to another on chip resource such as a DAC or main memory through DMA on the system bus.

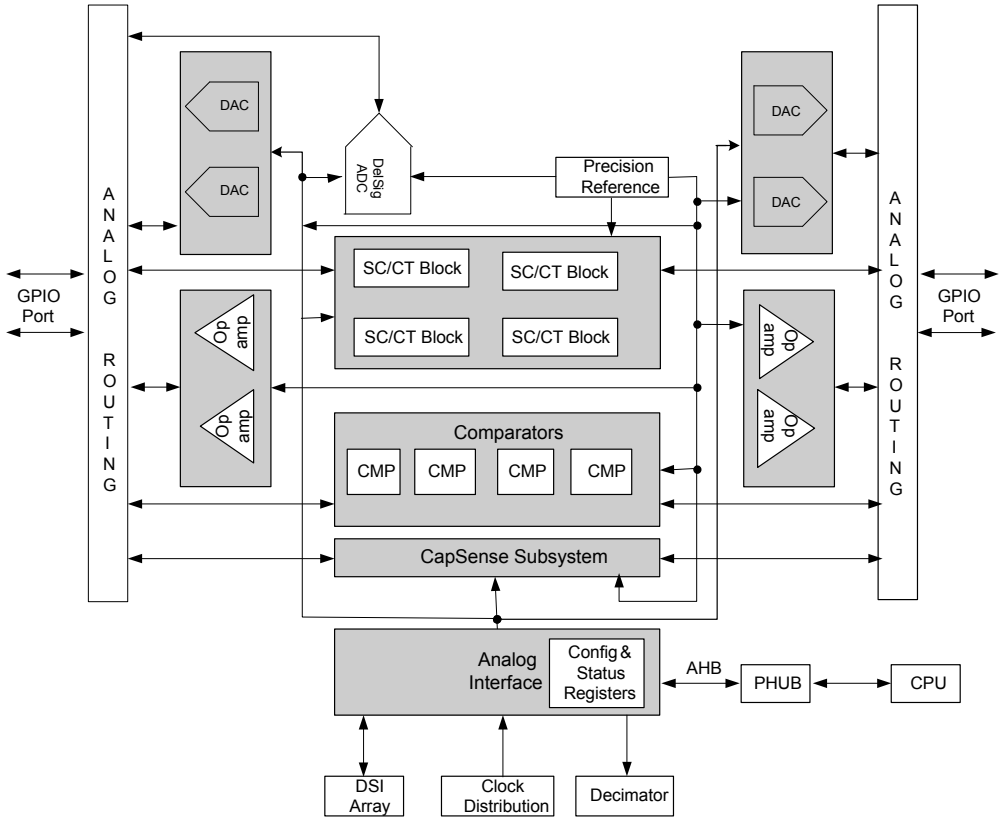
Data movement in or out of the DFB is typically controlled by the system DMA controller but can be moved directly by the MCU.

8. Analog Subsystem

The analog programmable system creates application specific combinations of both standard and advanced analog signal processing blocks. These blocks are then interconnected to each other and also to any pin on the device, providing a high level of design flexibility and IP security. The features of the analog subsystem are outlined here to provide an overview of capabilities and architecture.

- Flexible, configurable analog routing architecture provided by analog globals, analog mux bus, and analog local buses.
- High resolution delta-sigma ADC.
- Up to four 8-bit DACs that provide either voltage or current output.
- Four comparators with optional connection to configurable LUT outputs.
- Up to four configurable switched capacitor/continuous time (SC/CT) blocks for functions that include opamp, unity gain buffer, programmable gain amplifier, transimpedance amplifier, and mixer.
- Up to four opamps for internal use and connection to GPIO that can be used as high current output buffers.
- CapSense subsystem to enable capacitive touch sensing.
- Precision reference for generating an accurate analog voltage for internal analog blocks.

Figure 8-1. Analog Subsystem Block Diagram



The PSoC Creator software program provides a user friendly interface to configure the analog connections between the GPIO and various analog resources and connections from one analog resource to another. PSoC Creator also provides component libraries that allow you to configure the various analog blocks to perform application specific functions (PGA, transimpedance amplifier, voltage DAC, current DAC, and so on). The tool also generates API interface libraries that allow you to write firmware that allows the communication between the analog peripheral and CPU/Memory.

8.1 Analog Routing

The CY8C38 family of devices has a flexible analog routing architecture that provides the capability to connect GPIOs and different analog blocks, and also route signals between different analog blocks. One of the strong points of this flexible routing architecture is that it allows dynamic routing of input and output connections to the different analog blocks.

For information on how to make pin selections for optimal analog routing, refer to the application note, AN58304 - PSoC® 3 and PSoC® 5 - Pin Selection for Analog Designs.

8.1.1 Features

- Flexible, configurable analog routing architecture
- 16 analog globals (AG) and two analog mux buses (AMUXBUS) to connect GPIOs and the analog blocks
- Each GPIO is connected to one analog global and one analog mux bus
- Eight analog local buses (abus) to route signals between the different analog blocks
- Multiplexers and switches for input and output selection of the analog blocks

8.1.2 Functional Description

Analog globals (AGs) and analog mux buses (AMUXBUS) provide analog connectivity between GPIOs and the various analog blocks. There are 16 AGs in the CY8C38 family. The analog routing architecture is divided into four quadrants as shown in Figure 8-2. Each quadrant has four analog globals (AGL[0..3], AGL[4..7], AGR[0..3], AGR[4..7]). Each GPIO is connected to the corresponding AG through an analog switch. The analog mux bus is a shared routing resource that connects to every GPIO through an analog switch. There are two AMUXBUS routes in CY8C38, one in the left half (AMUXBUSL) and one in the right half (AMUXBUSR), as shown in Figure 8-2 on page 53.

Table 11-2. DC Specifications *(continued)*

Parameter	Description	Conditions		Min	Typ	Max	Units
	Sleep Mode[26]						
	CPU OFF RTC = ON (= ECO32K ON, in low power mode) Sleep timer = ON (= ILO ON at 1 kHz) [27] WDT = OFF I^2C Wake = OFF Comparator = OFF POR = ON SIO Pins in single ended input, unregulated output mode	$V_{DD} = V_{DDIO}$ = 4.5 V–5.5 V	T = –40 °C	–	1.1	2.3	µA
			T = 25 °C	–	1.1	2.2	µA
			T = 85 °C	–	15	30	µA
			T = 125 °C	–	20.3	30	µA
		$V_{DD} = V_{DDIO}$ = 2.7 V–3.6 V	T = –40 °C	–	1	2.2	µA
			T = 25 °C	–	1	2.1	µA
			T = 85 °C	–	12	28	µA
			T = 125 °C	–	18.5	28	µA
		$V_{CC} = V_{DDIO}$ = 1.71 V–1.95 V	T = 25 °C	–	2.2	4.2	µA
			T = 125 °C	–	16.2	28	µA
	Comparator = ON CPU = OFF RTC = OFF Sleep timer = OFF WDT = OFF I^2C Wake = OFF POR = ON SIO Pins in single ended input, unregulated output mode	$V_{DD} = V_{DDIO}$ = 2.7 V–3.6 V	T = 25 °C	–	2.2	2.7	µA
	I^2C Wake = ON CPU = OFF RTC = OFF Sleep timer = OFF WDT = OFF Comparator = OFF POR = ON SIO Pins in single ended input, unregulated output mode	$V_{DD} = V_{DDIO}$ = 2.7 V–3.6 V	T = 25 °C	–	2.2	2.8	µA

Notes
26. If Vccd and Vcca are externally regulated, the voltage difference between Vccd and Vcca must be less than 50 mV.
27. Sleep timer generates periodic interrupts to wake up the CPU. This specification applies only to those times that the CPU is off.

Table 11-7. GPIO AC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
TriseF	Rise time in Fast Strong Mode[30]	3 V Vddio Cload = 25 pF	–	–	12	ns
TfallF	Fall time in Fast Strong Mode[30]	3 V Vddio Cload = 25 pF	–	–	12	ns
TriseS	Rise time in Slow Strong Mode[30]	3 V Vddio Cload = 25 pF	–	–	60	ns
TfallS	Fall time in Slow Strong Mode[30]	3 V Vddio Cload = 25 pF	–	–	60	ns
Fgpioout	GPIO output operating frequency					
	3 V ≤ Vddio ≤ 5.5 V, fast strong drive mode	90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	33	MHz
		90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	24	MHz
	1.71 V ≤ Vddio < 3 V, fast strong drive mode	90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	20	MHz
		90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	16	MHz
	3 V ≤ Vddio ≤ 5.5 V, slow strong drive mode	90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	7	MHz
		90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	7	MHz
	1.71 V ≤ Vddio < 3 V, slow strong drive mode	90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	3.5	MHz
		90/10% Vddio into 25 pF, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	3.5	MHz
Fgpioin	GPIO input operating frequency					
	1.71 V ≤ Vddio ≤ 5.5 V	90/10% better than 60/40 duty cycle, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	66	MHz
		90/10% better than 60/40 duty cycle, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	50	MHz

Figure 11-11. SIO Output Rise and Fall Times, Fast Strong Mode, V_{DDIO} = 3.3 V, 25 pF Load

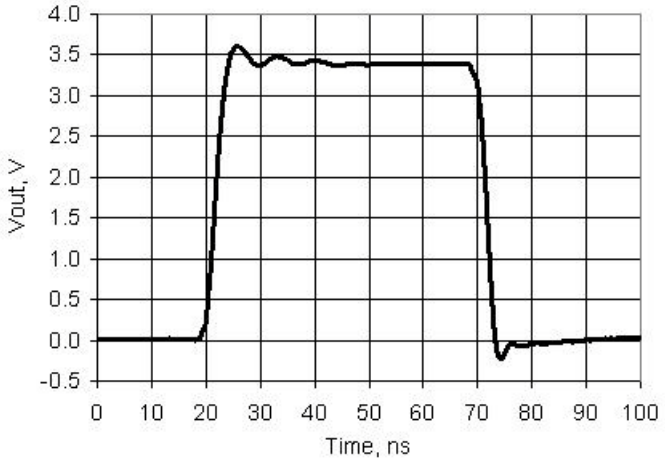
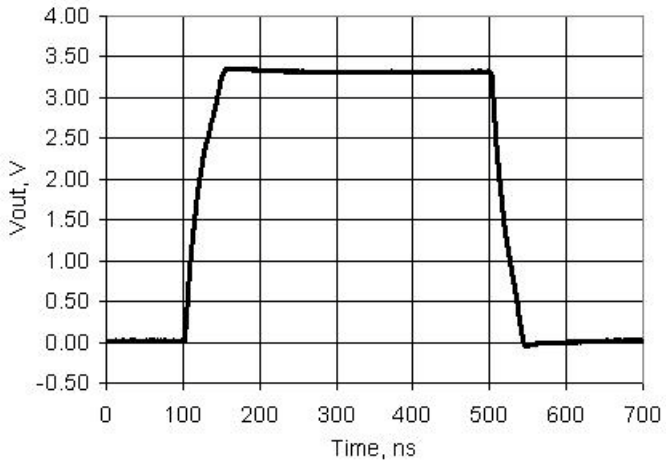


Figure 11-12. SIO Output Rise and Fall Times, Slow Strong Mode, V_{DDIO} = 3.3 V, 25 pF Load



11.4.3 USBIO

Table 11-10. USBIO DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
Rusbi	USB D+ pull up resistance	With idle bus	0.900	-	1.575	kΩ
Rusba	USB D+ pull up resistance	While receiving traffic	1.425	-	3.090	kΩ
Vohusb	Static output high	15 kΩ ±5% to Vss, internal pull up enabled	2.8	-	3.6	V
Volusb	Static output low	15 kΩ ±5% to Vss, internal pull up enabled	-	-	0.3	V
Vihgpio	Input voltage high, GPIO mode	$V_{DDD} \geq 3$ V	2	–	–	V
Vilgpio	Input voltage low, GPIO mode	$V_{DDD} \geq 3$ V	–	–	0.8	V
Vohgpio	Output voltage high, GPIO mode	Ioh = 4 mA, Vddio ≥ 3 V	2.4	-	-	V
Volgpio	Output voltage low, GPIO mode	Iol = 4 mA, Vddio ≥ 3 V	-	-	0.3	V
Vdi	Differential input sensitivity	|(D+)-(D-)|	-	-	0.2	V
Vcm	Differential input common mode range		0.8	-	2.5	V
Vse	Single ended receiver threshold		0.8	-	2	V
Rps2	PS/2 pull up resistance	In PS/2 mode, with PS/2 pull up enabled	3	-	7	kΩ
Rext	External USB series resistor	In series with each USB pin	21.78 (-1%)	22	22.22 (+1%)	Ω
Zo	USB driver output impedance	Including Rext, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	28	-	44	Ω
		Including Rext, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	28	-	46	Ω
Cin	USB transceiver input capacitance		-	-	20	pF
Iil [35]	Input leakage current (absolute value)	25°C, Vddio = 3.0 V	-	-	2	nA

Note
35. Based on device characterization (not production tested).

11.4.4 XRES

Table 11-13. XRES DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
Vih	Input voltage high threshold	CMOS Input, PRT[x]CTL = 0	0.7 × Vddio	-	-	V
Vil	Input voltage low threshold	CMOS Input, PRT[x]CTL = 0	-	-	0.3 × Vddio	V
Rpullup	Pull up resistor		3.5	5.6	8.5	kΩ
Cin	Input capacitance[30]		-	3	-	pF
Vh	Input voltage hysteresis (Schmitt-Trigger)[30]		-	100	-	mV
Idiode	Current through protection diode to Vddio and Vssio		-	-	100	µA

Table 11-14. XRES AC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
Treset	Reset pulse width		1	-	-	µs

11.5 Analog Peripherals

Specifications are valid for -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

11.5.1 Opamp

Table 11-15. Opamp DC Specifications

Parameter	Description	Conditions	Min	Typ	Max	Units
Vioff	Input offset voltage	-40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	-	-	±2.5	mV
		-40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	-	-	±5.0	mV
TCVos	Input offset voltage drift with temperature	Power mode = high	–	–	±30	µV / °C
Ge1	Gain error, unity gain buffer mode	Rload = 1 kΩ	-	-	±0.1	%
Vi	Input voltage range		Vssa	-	Vdda	mV
Vo	Output voltage range	Output load = 1 mA	Vssa + 50	-	Vdda - 50	mV
Iout	Output current	Output voltage is between Vssa +500 mV and Vdda -500 mV, and Vdda > 2.7 V, -40°C ≤ Ta ≤ 85°C and Tj ≤ 100°C	25	-	-	mA
		Output voltage is between Vssa +500 mV and Vdda -500 mV, and Vdda > 2.7 V, -40°C ≤ Ta ≤ 125°C and Tj ≤ 150°C	20	-	-	mA
Iout	Output current	Output voltage is between Vssa +500 mV and Vdda -500 mV, and Vdda > 1.7 V and Vdda < 2.7 V	16	-	-	mA
I_{DD}	Quiescent current	Power mode = min	–	250	400	µA
		Power mode = low	–	250	400	µA
		Power mode = med	–	330	950	µA
		Power mode = high	–	1000	2500	µA
CMRR	Common mode rejection ratio[30]		80	–	–	dB
PSRR	Power supply rejection ratio	Vdda ≥ 2.7 V	85	–	–	dB
		Vdda < 2.7 V	70	–	–	dB

Figure 11-16. Opamp Voffset Histogram, 3388 samples/847 parts, 25 °C, Vdda = 5 V

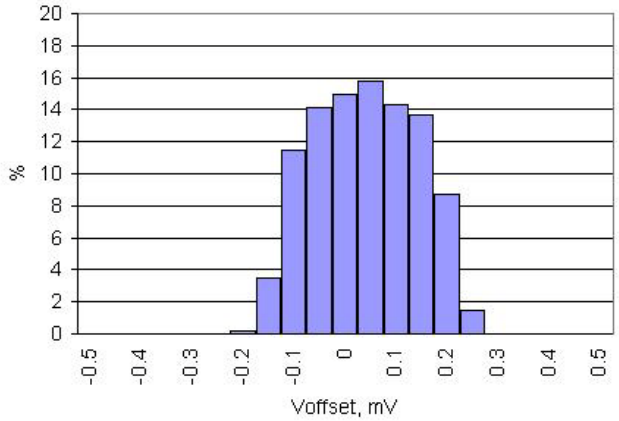


Figure 11-17. Opamp Voffset vs Temperature, Vdda = 5 V

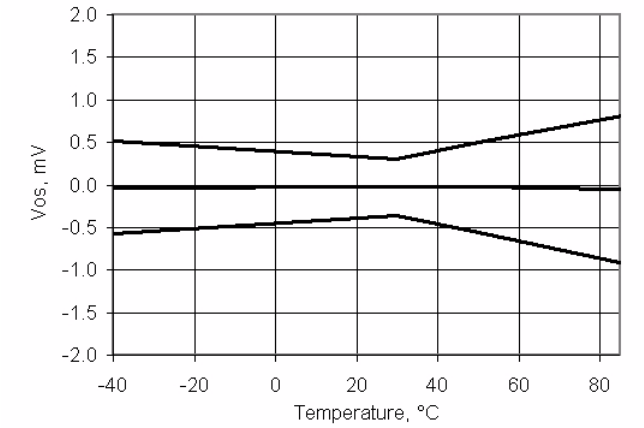


Figure 11-18. Opamp Voffset vs Vcommon and Vdda, 25 °C

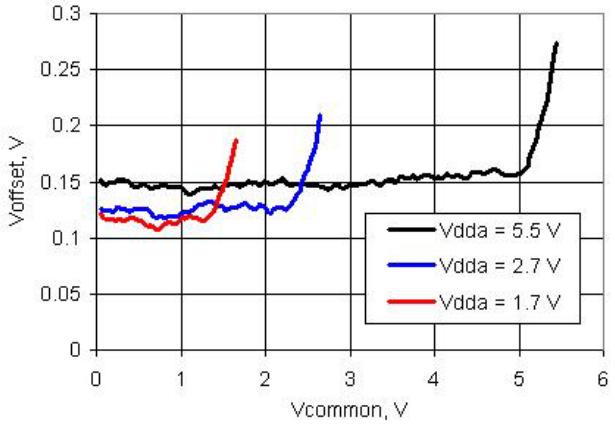


Figure 11-19. Opamp Output Voltage vs Load Current and Temperature, High Power Mode, 25 °C, Vdda = 2.7 V

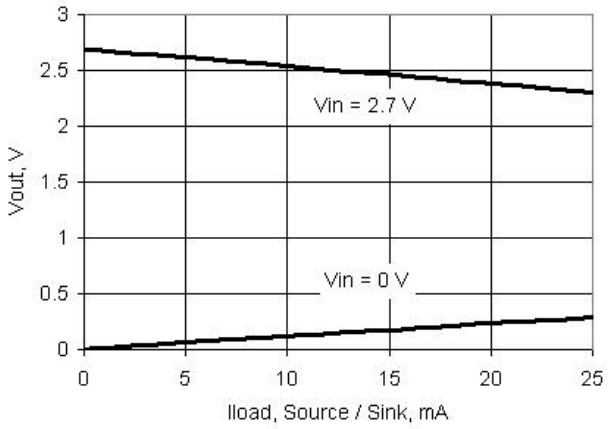


Table 11-23. Delta-sigma ADC RMS Noise in Counts vs. Input Range and Sample Rate, 20-bit, External Reference, Differential

Sample rate, sps	Input Voltage Range				
	±VREF	±VREF / 2	±VREF / 4	±VREF / 8	±VREF / 16
8	0.70	0.84	1.02	1.40	2.65
11.3	0.69	0.86	0.96	1.40	2.69
22.5	0.73	0.82	1.25	1.77	2.67
45	0.76	0.94	1.02	1.76	2.75
61	0.75	1.01	1.13	1.65	2.98
170	0.75	0.98	INVALID OPERATING REGION		
187	0.73				

Figure 11-28. Delta-sigma ADC DNL vs Output Code, 16-bit, 48 ksps, 25 °C V_{DDA} = 3.3 V

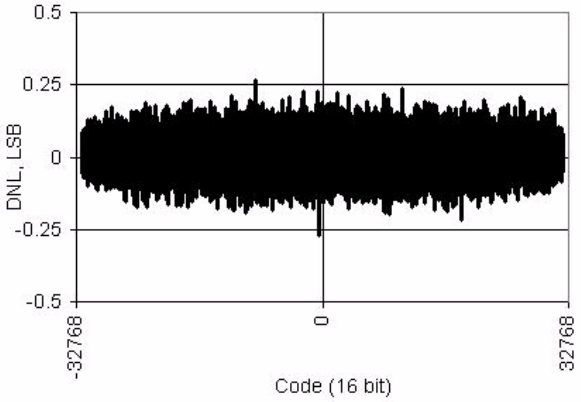


Figure 11-29. Delta-sigma ADC INL vs Output Code, 16-bit, 48 ksps, 25 °C V_{DDA} = 3.3 V

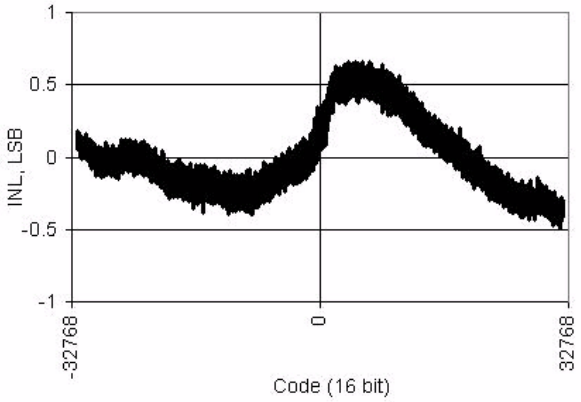


Table 11-28. IDAC (Current Digital-to-Analog Converter) DC Specifications *(continued)*

Parameter	Description	Conditions	Min	Typ	Max	Units
I_{DD}	Operating current, code = 0	Low speed mode, source mode, range = 31.875 µA	–	44	100	µA
		Low speed mode, source mode, range = 255 µA,	–	33	100	µA
		Low speed mode, source mode, range = 2.04 mA	–	33	100	µA
		Low speed mode, sink mode, range = 31.875 µA	–	36	100	µA
		Low speed mode, sink mode, range = 255 µA	–	33	100	µA
		Low speed mode, sink mode, range = 2.04 mA	–	33	100	µA
		High speed mode, source mode, range = 31.875 µA	–	310	500	µA
		High speed mode, source mode, range = 255 µA	–	305	500	µA
		High speed mode, source mode, range = 2.04 mA	–	305	500	µA
		High speed mode, sink mode, range = 31.875 µA	–	310	500	µA
		High speed mode, sink mode, range = 255 µA	–	300	500	µA
		High speed mode, sink mode, range = 2.04 mA	–	300	500	µA

Figure 11-32. IDAC INL vs Input Code, Range = 255 µA, Source Mode

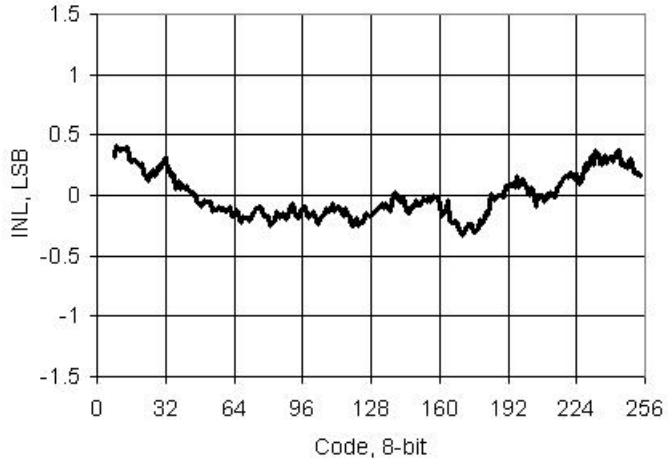
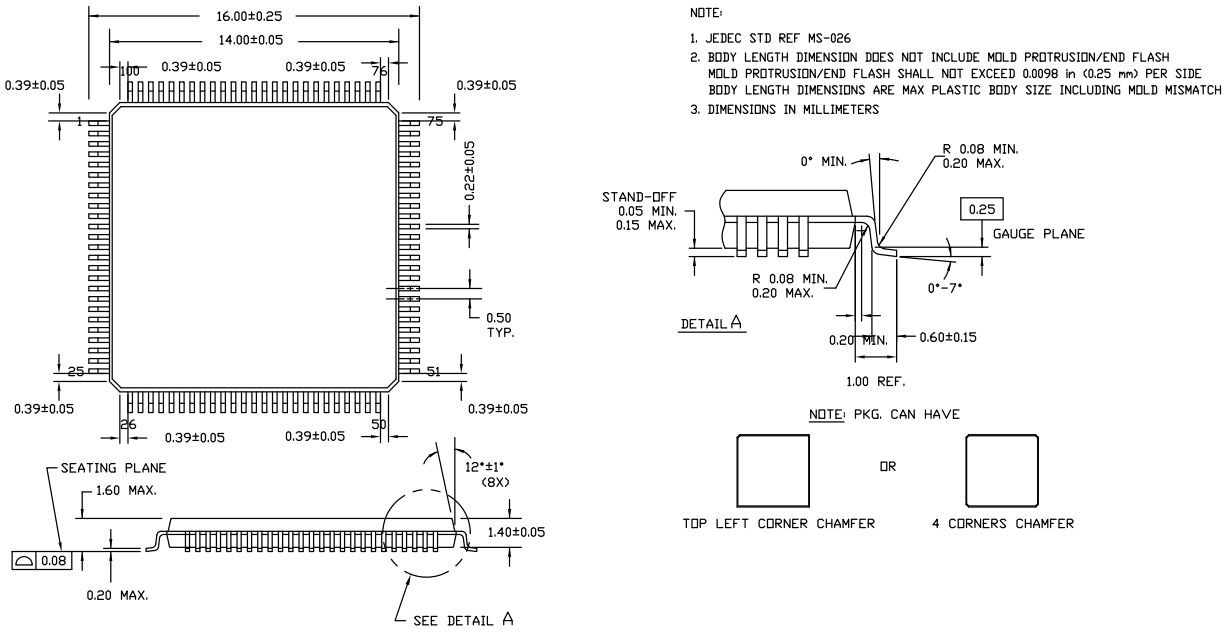


Figure 13-2. 100-pin TQFP (14 × 14 × 1.4 mm) A100SA Package Outline, 51-85048



51-85048 *I

17. Revision History *(continued)*

Description Title: PSoC® 3: CY8C38 Automotive Family Datasheet, Programmable System-on-Chip (PSoC®) Document Number: 001-54683				
Rev.	**ECN**	**Submission Date**	**Orig. of Change**	**Description of Change**
*H	4094193	08/30/2013	NFB / ANMD	Changed status from Preliminary to Final. Updated Features: Added Note 1 and referred the same note at the end in “16-bit mode, 48 ksps, 83-dB SINAD, ±2-bit INL, ±1-bit DNL”. Updated Architectural Overview: Updated Figure 1-1. Added Note 5 and referred the same note in “features” in “The heart of the analog subsystem is a fast, accurate, configurable delta-sigma ADC with these features”. Updated Pinouts: Updated Figure 2-5. Updated Memory: Updated EEPROM: Updated description. Updated Nonvolatile Latches (NVLs): Updated Table 5-2 and Table 5-3. Updated Memory Map: Updated I/O Port SFRs: Updated xdata Space: Updated Table 5-5. Updated Digital Subsystem: Updated Universal Digital Block: Updated PLD Module: Updated Figure 7-3. Updated I^2C: Updated description. Updated Analog Subsystem: Updated Delta-sigma ADC: Updated Table 8-1 Updated Programmable SC/CT Blocks: Updated PGA: Updated Table 8-3.